Nanoscale Imaging of Current Density with a Single-Spin Magnetometer

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Supporting Information

ABSTRACT: Charge transport in nanostructures and thin films is fundamental to many phenomena and processes in science and technology, ranging from quantum effects and electronic correlations in mesoscopic physics, to integrated charge- or spin-based electronic circuits, to photoactive layers in energy research. Direct visualization of the charge flow in such structures is challenging due to their nanometer size and the itinerant nature of currents. In this work, we demonstrate noninvasive magnetic imaging of current density in two-dimensional conductor networks including metallic nanowires and carbon nanotubes. Our sensor is the electronic spin of a diamond nitrogen-vacancy center attached to a scanning tip and operated under ambient conditions. Using a differential measurement technique, we detect DC currents down to a few μA with a current density noise floor of ∼2 × 10^8 A/cm². Reconstructed images have a spatial resolution of typically 50 nm, with a best-effort value of 22 nm. Current density imaging offers a new route for studying electronic transport and conductance variations in two-dimensional materials and devices, with many exciting applications in condensed matter physics and materials science.

KEYWORDS: Magnetic imaging, scanning probe microscopy, quantum sensing, single spin, diamond nitrogen-vacancy center, electron paramagnetic resonance

Noninvasive detection of currents is possible thanks to the long-range magnetic field that appears near moving charges, according to the law of Biot and Savart. 1 Although a map of the Oersted field does not directly reproduce an image of current flow, the current density can for some geometries be rigorously reconstructed. A particularly important class of conductors are two-dimensional structures, such as patterned electronic circuits, semiconductor electron and hole gases, or organic and inorganic thin films. In this case it is possible to reconstruct the two-dimensional current density from a single component of the magnetic field, recorded in a plane at a fixed distance over the conductor. 2 Millimeter-to-micrometer current density mapping has been performed by scanning Hall probes, 3 magneto-optical methods, 4 magnetoresistance probes, 5 scanning SQUIDs, 6–10 and diamond chips with large ensembles of nitrogen-vacancy (NV) centers. 9–13

Despite of many challenges, there is a strong incentive to extend current density mapping to higher resolution, especially if the nanometer regime can be reached. At the nanoscale, many interesting phenomena may be explored, such as branched electron flow, 14,15 weak localization and universal conductance fluctuations, 16 edge conductance, 17,18 dissipationless currents, 19,20 or impurity backscattering. 21,22 A nanometer scale imaging capability could hence play an important role in mesoscopic condensed matter physics and guide the development of novel materials and circuits. Impressive advances in submicrometer current density mapping have recently been made with nano-SQUIDs fabricated on the ends of pulled glass capillaries. 23–25

In this work, we demonstrate sub-30 nm-resolution imaging of current density in patterned nanowire devices at room temperature using a scanning diamond magnetometer. We find that the technique is ideally suited for current density mapping, as the scanning sensor spin is point-like and naturally provides a single component of the vector magnetic field. We further show that DC and microwave currents can be mapped and reconstructed separately, providing two independent means for analyzing local current flow. Finally, we demonstrate the potential of the technique by imaging currents flowing in a bundle of carbon nanotubes.

Diamond magnetometry uses a single defect spin in a diamond tip to sense the local magnetic field near a sample. 26 Optically detected electron paramagnetic resonance (EPR) is used to probe the resonance of the spin via application of a microwave field and fluorescence detection. 27,28 Because the spin resonance shifts with DC magnetic field via the Zeeman effect, the resonance frequency is directly proportional to the local magnetic field. By controlled scanning of the diamond tip over the sample, high-resolution magnetic images can be obtained. Recent work has mostly focused on magnetic nanostructures, 29 including single electron spins, 30 thin

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magnetic films, and surfaces of superconductors. In the present work we apply the technique to image charge currents via the Oersted magnetic field.

The key element in our measurement apparatus is a scanning tip with a single NV center at its apex (Figure 1). Peripheral instrumentation permits optical pumping and readout of the NV spin and its manipulation by microwave magnetic fields. The tips are prepared by picking up nanoparticles with a commercial atomic force microscopy cantilever. The (θ, ϕ) vector orientation of the sensor, which is determined by the symmetry axis of attached NV centers (see Figure 1), is calibrated in a separate EPR spectroscopy measurement to within a few degrees. The stand-off distance z between the NV center and the sample surface is inferred from a one-dimensional line scan across a current-carrying nanowire (see below).

The magnetic field is measured by recording a continuous-wave EPR spectrum and determining the peak frequency of the resonance using a Lorentzian fit (see Figure 2a–c). To eliminate long-term electrical or thermal drift and to discriminate the current-induced field from other magnetic fields, we have implemented a differential measurement technique. At each measurement location, two EPR spectra are recorded with a positive (+I) or negative (−I) source current applied to the device. Spectra are taken by square wave modulation of the DC source at 1 kHz and binning photon counts in synchrony with the modulation. In this way, low-frequency drift and background signals are efficiently rejected. The difference between the EPR peak frequencies of the two spectra, \( \delta \omega = \frac{1}{2}(\omega_{+I} - \omega_{-I}) \) (see Figure 2b), then directly corresponds to the component of the Oersted field that is parallel to the NV axis,

\[
B_I(x, y) = B_{Oe}(x, y) \cdot \mathbf{n} = \frac{\delta \omega(x, y)}{\gamma}
\]

where we have explicitly stated that \( \delta \omega(x, y) \) is a function of position. \( \gamma = 28 \text{ GHz/T} \) is the gyromagnetic ratio of the electronic spin and \( \mathbf{n} = (\sin \phi \cos \theta, \sin \theta \sin \phi, \cos \phi \cos \theta) \) is the unit vector along the NV symmetry axis (see Figure 1). The Lorentzian fit also yields values for the line width parameter \( \Omega \) and the optical contrast \( \epsilon \) (see Figure 2b) which can be used to infer the local microwave field \( B_{mw}(x, y) \).
Because both the DC and microwave magnetic fields have the same spatial distribution, it is practical to image the current flowing in the wire by plotting the line width parameter \( \delta \omega \) as a function of position \((x, y)\) (see eq 2). The resulting magnetic image, shown in Figure 3b, clearly reflects the geometry of the underlying structure. Since this image is taken with an NV center oriented nearly parallel to the z axis, the magnetic field is positive to one side of the wire while it is negative to the other side.

To demonstrate two-dimensional imaging, we use a Y-shaped structure where the current is injected at the bottom (S) and collected by the two arms at the top (D1 and D2, see electron micrograph in Figure 3a). To form a magnetic image of the current flowing in this device, the diamond tip is scanned laterally in a plane at fixed z spacing from the top of the wire (Figure 1). The spacing is maintained by briefly approaching and retracting the tip by a known amount before each point. The resulting magnetic image, shown in Figure 3b, clearly reflects the geometry of the underlying structure. Since this image is taken with an NV center oriented nearly parallel to the z axis, the magnetic field is positive to one side of the wire while it is negative to the other side.

In addition to the DC magnetic field, we can also image the microwave magnetic field by plotting the line width parameter \( \Omega \) (Figure 3c). In this measurement a high microwave power above the EPR saturation threshold is applied, and the line width varies as \( \Omega \approx \frac{1}{\sqrt{2}} \gamma B_\perp \) (see eq 2). Because both the DC and microwave fields originate from the same conductor (and neglecting the effects of skin depth and wavelength), it can be expected that the two fields have the same spatial distribution. The vector component picked up in the two imaging modes is, however, orthogonal. While the DC image corresponds to the magnetic field parallel to the spin orientation \( n \), the microwave image represents the component transverse to \( n \). This feature can be observed in Figure 3b,c, where the DC field passes through zero right above the

\[
B_\perp(x, y) = |B_{\text{m}}(x, y) \times n| \approx \frac{\sqrt{2}\Omega(x, y)}{\gamma} \frac{|\epsilon(x, y)|}{\epsilon_{\text{max}}}
\]  

(2)

where \( \epsilon_{\text{max}} \) is the saturated optical contrast. \cite{eq1, eq2, eq3} Equation 2 has two important limiting cases. At high microwave power above the saturation threshold, the line width \( \Omega \approx \frac{1}{\sqrt{2}} \gamma B_\perp \) is proportional to \( B_\perp \) due to power broadening. For low microwave power, \( \Omega \) is constant and the optical contrast \( \epsilon \propto B_\perp \) is proportional to the absorbed microwave power.

To develop our current imaging technique, we fabricate several sets of nanowire test devices with different geometries, including straight sections, turns, kinks, and splits. The metallic nanowires are made by e-beam lithography and Pt deposition and have cross sections between 50 \( \times \) 50 and 100 \( \times \) 100 nm\(^2\) (see ref 38). The devices can be connected to both a DC and microwave source \((\sim 2.7 \text{ GHz})\) such that the same nanowire can be used for producing DC fields and actuating the EPR transition. To test a device, we scan the NV center laterally across a straight section of a nanowire while applying a current and record the differential line shift \( \delta \omega \) as a function of x position (Figure 2d,e). This line scan can be compared to an analytical model and allow us to accurately calibrate the stand-off distance \( z \); for the tips used in this study, stand-offs were typically between 25 and 100 nm.

The line scans also provide an estimate of the minimum detectable current. For DC currents, this value is around \( \sim 1 \mu\text{A} \) (Figure 2f). The minimum detectable microwave current is in principle much lower and ultimately limited by the \( T_1 \) time of the NV spin. \cite{eq4} For \( T_1 = 10 \mu\text{s} \), the magnetic field noise is \( \sim 2.5 \text{nT/Hz} \), corresponding to a noise in the microwave current of a few nA/Hz. However, due to frequency jitter in the EPR resonance, this value cannot be easily reached, and in practice, the microwave sensitivity is similar to the DC sensitivity. \cite{eq2}

**Figure 3.** Two-dimensional images of geometry, magnetic field and reconstructed current density for a Pt nanowire test device. (a) Scanning electron micrograph of the device indicating the direction of current flow \((I = 90 \mu\text{A})\). (b) Image (raw data) of the differential line shift, representing the component \( B_\perp \) of the DC magnetic field that is parallel to the NV center axis \( n \). The scanning NV center had a stand-off \( z = 75 + 8 \text{ nm} \) and an orientation \((\theta, \phi) = (2', 322')\). Images are composed of an array of 50 \( \times \) 50 pixels spaced by 60 nm, where each pixel required 1 min of averaging. The pixelated areas correspond to regions where the EPR spectrum was not well-resolved and the Lorentzian fit error was large. (c) Image (raw data) of the line width, representing the component \( B_\perp \) of the microwave magnetic field that is transverse to \( n \). (d) Current density image \( |J(x, y)| \) reconstructed from \( B_\perp \) using a spatial filtering parameter of \( x = 215 \text{ nm} \). The corresponding reconstruction from \( B_\perp \) is provided in Supporting Figure S5. (e) \( J_x \) and \( J_y \) components of the current density. All scale bars are 1 \( \mu\text{m} \).
Roth et al. 2 As discussed in the Supporting Information (ref 38), the reconstructed current density $J_{\text{reconstructed}}$ for decreasing values of the spatial filter parameter $\lambda$. (c) One-dimensional plot along the dashed line in (b). The blue solid line represents the data, and the red dashed curve represents the conductor shape (green) convolved with a Gaussian. The spatial resolution, indicated by the 15 ± 2 nm, orientation was $(\theta, \phi) = (20^\circ, 140^\circ)$, and grid spacing was 20 nm. (d) The current density $|\mathbf{J}|$ reconstructed for the nanowire current was done over dashed line in pane; b and over the nanowire height ($h \sim 100$ nm). Background current represents background current density multiplied by conductor cross-section.

Figure 4. Demonstration of 22 nm spatial resolution. (a) Magnetic image of an elbow-shaped Pt nanowire with a source current of 96 $\mu$A. The sensor stand off was $z = 35 \pm 2$ nm, orientation was $(0, 0, 0)$, and grid spacing was 20 nm. (b) The current density $|\mathbf{J}|$ for the red dashed curve represents the conductor shape (green) convolved with a Gaussian. The spatial resolution, indicated by the 15–85% rise of the signal, is 22 ± 2 nm. (d) Root-mean-square noise of the background (dotted rectangle in b) and peak current density of the wire (hollow dot in b) as a function of $\lambda$. (e) Integrated current and corresponding background current as a function of $\lambda$. The failure of the reconstruction for $\lambda < \lambda_{\text{crit}}$ (vertical dashed line) can be clearly seen. Integration of nanowire current was done over dashed line in pane; b and over the nanowire height ($h \sim 100$ nm). Background current represents background current density multiplied by conductor cross-section.

In a next step, we reconstruct the two-dimensional current density $J(x, y) = (j_x, j_y)$ from the DC magnetic image $B_\parallel(x, y)$. This can be achieved by inverting Biot and Savart’s law. For this purpose we adapt an inverse filtering technique described by Roth et al. 2 As discussed in the Supporting Information (ref 38), the reconstructed current density $J_{\text{reconstructed}}$ in Fourier space is

$$J_x(k_x, k_y) = \frac{w(k, \lambda)k_y}{g(k, z)}[e_xk_y - e_yk_x + ie_zk]B_\parallel(k_x, k_y, z)$$

$$J_y(k_x, k_y) = \frac{w(k, \lambda)k_x}{g(k, z)}[e_yk_y - e_yk_x - ie_zk]B_\parallel(k_x, k_y, z)$$

where $k_x$ and $k_y$ are $k$-space vectors, $k = (k_x^2 + k_y^2)^{1/2}$ and where $(e_x, e_y, e_z) = n$ is the sensor orientation. A similar set of equations can be derived to infer $J(x, y)$ from the microwave field $B_\perp(x, y)$.

The function $g(k, z)$ is the Green’s function

$$g(k, z) = \frac{\mu g_{\text{eff}}}{2} e^{-kz}$$

where $g_{\text{eff}} = (1 - e^{-\lambda z})/k$ is an effective thickness and $h$ the physical thickness of the conductor (see Figure 1). In addition, $w(k, \lambda)$ is a window function required to suppress noise at high spatial frequencies $k$ where $g(k, z)$ is small. We use a Hanning window,

$$w(k, \lambda) = \begin{cases} \frac{1}{2} \left[ 1 + \cos \left( \frac{1-k\lambda}{2} \right) \right] & \text{if } |k| < 2\pi/\lambda \\ 0 & \text{otherwise} \end{cases}$$

with cutoff wavelength $\lambda$. The wavelength $\lambda$ plays the role of a spatial filtering parameter that can be tuned to adjust image resolution and noise rejection (see below). We have also experimented with other window functions and found the Hanning window to provide a good compromise between noise suppression and avoidance of artifacts due to its smooth turn-on with the wave vector $k$. Beside the Hanning filter, several other window functions were found to significantly improve the quality of the reconstruction.

Figure 3d–f displays the results of the reconstruction, which include the magnitude of the current density $|\mathbf{J}|$ as well as the individual components $j_x$ and $j_y$. Given that the raw data is rather coarsely sampled and has limited signal-to-noise ratio (SNR), the quality of the reconstruction is quite remarkable. This apparent improvement is expected since the reconstruction process inherently acts as a spatial low-pass filter through the cutoff parameter $\lambda$. Excellent agreement is found with the scanning electron micrograph of Figure 3a. Even fine features, such as the zigzag structure at the top left corner, are reasonably well-resolved, and positive and negative current densities are reliably reproduced. The magnitudes of the currents entering...
Table 1. Comparison of Mesoscopic Current Imaging Experiments

<table>
<thead>
<tr>
<th>sensor</th>
<th>reference</th>
<th>device</th>
<th>frequency</th>
<th>source current</th>
<th>resolution</th>
<th>temperature</th>
</tr>
</thead>
<tbody>
<tr>
<td>NV (ensemble)</td>
<td>Nowodzinski et al.\textsuperscript{11}</td>
<td>integrated circuit</td>
<td>DC</td>
<td>6 mA</td>
<td>~μm</td>
<td>295 K</td>
</tr>
<tr>
<td></td>
<td>Tetienne et al.\textsuperscript{13}</td>
<td>graphene</td>
<td>DC</td>
<td>0.8 mA</td>
<td>~μm</td>
<td>295 K</td>
</tr>
<tr>
<td>NV (single)</td>
<td>this work</td>
<td>Pt-NW, CNT\textsuperscript{23}</td>
<td>1 kHz</td>
<td>3 μA</td>
<td>22 nm</td>
<td>295 K</td>
</tr>
<tr>
<td></td>
<td>this work</td>
<td>Pt-NW, CNT\textsuperscript{23}</td>
<td>3 GHz</td>
<td>(3 μA)\textsuperscript{h}</td>
<td>(22 nm)\textsuperscript{h}</td>
<td>295 K</td>
</tr>
<tr>
<td></td>
<td>projected (see text)</td>
<td></td>
<td>1 MHz</td>
<td>&lt;10 nA</td>
<td>&lt;10 nm</td>
<td>295 K</td>
</tr>
<tr>
<td>SQUID</td>
<td>Nowack et al.\textsuperscript{2}</td>
<td>HgTe</td>
<td>0.2–8 kHz</td>
<td>15−1000 nA</td>
<td>3 μm\textsuperscript{c}</td>
<td>4.5–20 K</td>
</tr>
<tr>
<td></td>
<td>Anahory et al.\textsuperscript{24}</td>
<td>Pb-NW\textsuperscript{23}</td>
<td>10.4 kHz</td>
<td>25 nA</td>
<td>150 nm\textsuperscript{m}</td>
<td>4.2 K</td>
</tr>
<tr>
<td></td>
<td>Halbertal et al.\textsuperscript{25}</td>
<td>Cu/Pt-NW, CNT\textsuperscript{23}</td>
<td>6.56 kHz</td>
<td>10 μA</td>
<td>46 nm\textsuperscript{m}</td>
<td>4.2 K</td>
</tr>
<tr>
<td>magnetoresistive</td>
<td>Schrag et al.\textsuperscript{1}</td>
<td>Al</td>
<td>80 kHz</td>
<td>~1 mA</td>
<td>(40 nm)\textsuperscript{d}</td>
<td>295–475 K</td>
</tr>
</tbody>
</table>

\textsuperscript{a}NW = nanowire, Py = permalloy, CNT = carbon nanotube. \textsuperscript{b}Not measured, but similar to DC. \textsuperscript{c}Pick-up loop diameter. \textsuperscript{d}Estimate.

Figure 5. Imaging results for carbon nanotubes (CNTs). (a) Topographic image recorded using an atomic force microscope. The typical CNT height is 10 nm. (b) Image (raw data) of the differential line shift δω/γ, representing the DC magnetic field \( B_z \). (c) Image (raw data) of the optical contrast \( ε \), representing the microwave magnetic field \( B_z \). \( ε_{\text{max}} \) was 0.23. (d,e) Current density \( |J| \) and the mean baseline offset. Filter parameters were \( λ = 130 \) and 60 nm for panels d and e, respectively. Scale bars are 500 nm.

and exiting through the three arms quantitatively agree with Kirchhoff’s rule and the nominal source current.

A key feature of scanning diamond magnetometry is the technique’s potential for imaging with high spatial resolution and sensitivity. In our experiment, the resolution can be tuned through the filter parameter \( λ \). By reducing \( λ \), the resolution is refined up to the point where the noise in the reconstructed image becomes excessive (see Figure 4a,b). This occurs at a certain critical wavelength \( λ_{\text{crit}} \) that is of order of the tip stand off \( z \) and that is independent of the specific filter window used.

For Figure 4 \( λ_{\text{crit}} \approx 50 \) nm and \( z = 35 \) nm. The critical wavelength relates to the decay length of the exponential factor in the Green’s function \( g \propto e^{-λz} \) (eq 5). To estimate the image resolution, we inspect a line cut across the conductor for \( λ \approx λ_{\text{crit}} \) (dashed line in Figure 4b). We determine the spatial resolution by the \( x \) distance over which the signal rises from 15% to 85% between its minimum and maximum. This distance corresponds to two sigma of a Gaussian convolved with the conductor shape according to Sparrow’s resolution criterion.\textsuperscript{41,42} The 15−85% distance is about 22 nm for the \( λ = 55 \) nm reconstruction (Figure 4c). Note that the fastest possible signal rise supported by the reconstruction is approximately \( λ/4 = 14 \) nm (ref 38), but this value is not reached because the window filter suppresses high spatial frequencies already before reaching the cutoff wavelength \( λ \).

We can further determine the baseline noise in the current density and the integrated conductor current as a function of \( λ \) (Figures 4d,e). We find that both quantities are approximately constant when \( λ \) is chosen larger than the critical wavelength \( λ_{\text{crit}} \). For the data set in Figure 4, the standard deviation in the current density and the mean baseline offset are both of order 2 × 10\(^{4}\) A/cm\(^{2}\). This converts to a minimum detectable current \( \sim 1 \) μA (Figure 4e) in agreement with our earlier finding. Table 1 summarizes the results of the present study along with other high resolution current imaging experiments.

Finally, we explore the application of the technique to detect currents flowing in bundles of carbon nanotubes (CNTs). The CNTs were vertically grown on Si with Fe as the catalyst,\textsuperscript{43} and dispersed onto a quartz substrate, and contacted by e-beam lithography.\textsuperscript{38} Figure 5 shows an example of CNT imaging. The pick-up loop diameter, \( \theta \), and that both quantities are approximately constant when \( λ \) is chosen larger than the critical wavelength \( λ_{\text{crit}} \). For the data set in Figure 4, the standard deviation in the current density and the mean baseline offset are both of order 2 × 10\(^{4}\) A/cm\(^{2}\). This converts to a minimum detectable current of \( \sim 1 \) μA (Figure 4e), in agreement with our earlier finding. Table 1 summarizes the results of the present study along with other high resolution current imaging experiments.

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provides the strongest image contrast (Figure 5c). The corresponding line width $\Omega \approx 3$ MHz is approximately constant (Supporting Figure S6). Both the DC and microwave images can be reconstructed (Figures 5d,e), with significantly better resolution resulting from the microwave data. The current density images reveals interesting features about the CNT bundle; in particular, only a center portion of the bundle appears to be conducting while a number of side loops (arrows in Figure 5a) do not carry any measurable current.

In summary, we have shown that the technique of scanning diamond magnetometry enables two-dimensional imaging of current density with sub-30 nm spatial resolution and $\sim 1\mu$A sensitivity. The magnetic imaging process is passive, with no direct disturbance of the electron flow, and can be carried out under ambient conditions. Although the sensitivity of our measurements is presently far from that reported in state-of-the-art scanning SQUID experiments, where currents down to $\sim 25$ nA have been detected (see Table 1), further improvements can be expected as the diamond probe and acquisition techniques are being refined. For example, by replacing our nanodiamond probes with etched single-crystal diamond tips, a resolution below 10 nm should be reachable. Moreover, pulsed EPR techniques could be employed to detect signals via spin echoes, optimized phase-estimation protocols, and by efficient memory-assisted readout, with expected magnetic sensitivities below 10 nT/$\sqrt{\text{Hz}}$. The combined advances would lower the current sensitivity to near 1 nA (see Table 1). Such a capability would allow resolving even weak current density fluctuations and possibly provide new insight into the local conductance of two-dimensional materials in condensed matter physics.

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acs.nanolett.6b05304.

A description of the measurement apparatus and devices, the measurement protocol, the reconstruction procedure, microwave imaging, and additional data sets (PDF)

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The authors declare no competing financial interest.

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